

4115

DATASHEET

Specification Revision History:

Version	Date	Description
V1.0	2019/11	New
V1.1	2021/01	Modify Ordering Information
V1.2	2025/02	Modify Ordering Information
V1.3	2025/03	Add application precautions and overall typesetting.

FEATURES

- Simple low parts count
- Wide input voltage range:4.5V to 30V Up to 1.2A output current
- Single pin on/off and brightness_using DC voltage or PWM
- Up to 1MHz switching frequency
- Typical 5%output current accuracy
- Inherent open-circuit LED protection
- High efficiency(up to 97%)
- High-Side Current Sense
- Hysteretic Control:No Compensation
- Adjustable Constant LED Current
- SOT89-5/ESOP8 for large output power application
- RoHS compliant

APPLICATIONS

- Low voltage halogen replacement LEDs
- Automotive lighting
- Low voltage industrial lighting
- LED back-up lighting
- Illuminated signs
- SELV lighting
- LCD TV backlighting

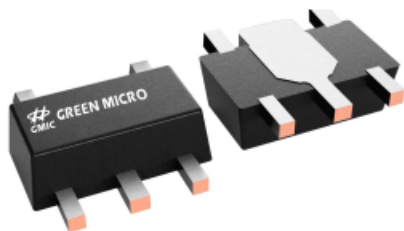
GENERAL DESCRIPTION

The 4115 is a continuous conduction mode inductive step-down converter,designed for driving single or multiple series connected LED efficiently from a voltage source higher than the total LED chain voltage.Thee device operates from an input supply between 4.5V and 30V and provides an externally adjustable output current of up to 1.2A.Dependent upon the supply voltage and external components,the 4115 can provide more than 30 watts of output power.

The 4115 includes the power switch and a high-side output current sensing circuit,which uses an external resistor to set the nominal average output current,and a dedicated DIM input accepts either a DC voltage or a wide range of pulsed dimming.Applying a voltage of 0.3V or lower to the DIM pin turns the output off and switches the device into a low current standby state.

The 4115 is available in SOT89-5 and packages

The appearance of the product

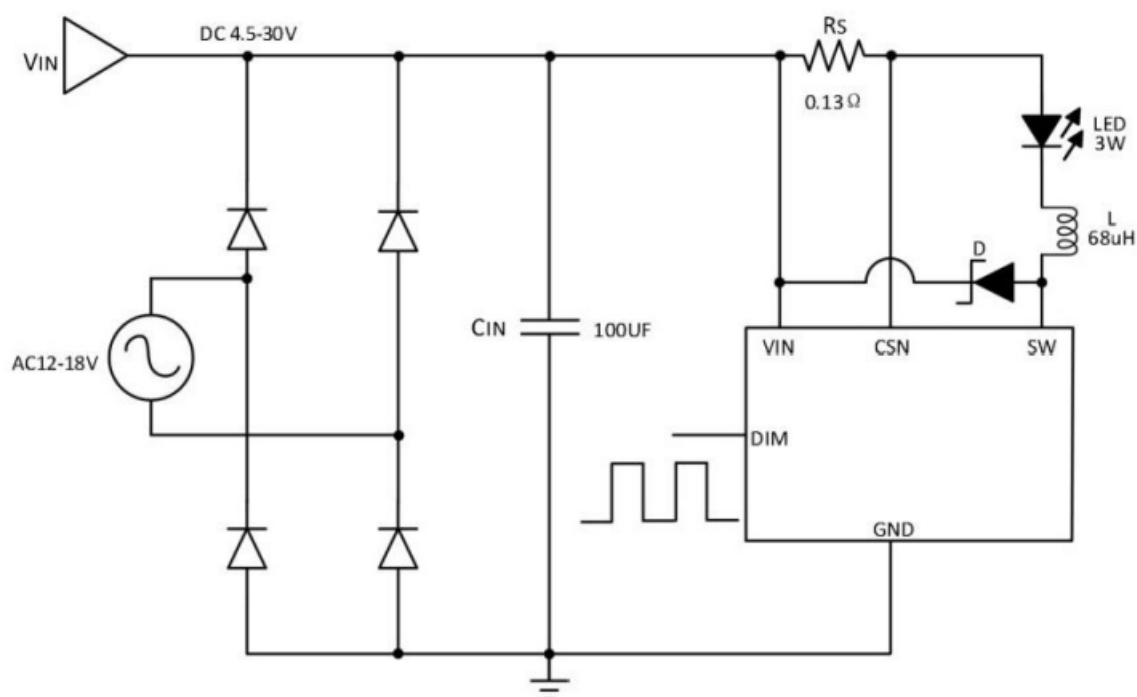


SOT-89-5

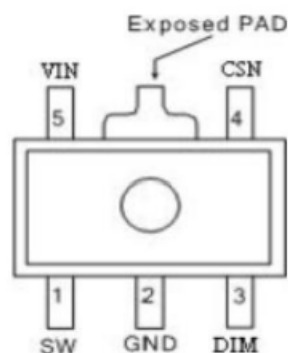
Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
PT4115E89(GMIC)	SOT-89	4115 0006	编带	1000PCS/盘

TYPICAL APPLICATION CIRCUIT



PIN ASSIGNMENT



N No.	PIN NAMES	DESCRIPTION
1	SW	Switch Output. SW is the drain of the internal N-Ch MOSFET switch.
2	GND	Signal and power ground. Connect directly to ground plane.
3	DIM	Logic level dimming input. Drive DIM low to turn off the current regulator. Drive DIM high to enable the current regulator.
4	CSN	Current sense input
5	VIN	Input Supply Pin. Must be locally bypassed.
-	Exposed PAD	Internally connected to GND. Mount on board for lower thermal resistance.
ESOP8 4,5	NC	No connection

ABSOLUTE MAXIMUM RATINGS (notel)

SYMBOL	ITEMS	VALUE	UNIT
V_{IN}	Supply Voltage	-0.3~40	V
SW	Drain of the internal power switch	-0.3~40	V
CSN	Current sense input (Respect to VIN)	+0.3~(-6.0)	V
DIM	Logic level dimming input	-0.3~12	V
I_{SW}	Switch output current	1.5	A
P_{DMAX}	Power Dissipation(Note 2)	1.5	W
P_{TR}	Thermal Resistance,SOT89-5 θ_{JA}	45	°C/W
P_{TR}	Thermal Resistance,ESOP8 θ_{JA}	40	°C/W
T_j	Operation Junction Temperature Range	-40 to 150	°C
T_{STG}	Storage Temperature	-55 to 150	°C
	ESD Susceptibility(Note 3)	2	kV

RECOMMENDED OPERATING RANGE

SYMBOL	ITEMS	VALUE	UNIT
V_{IN}	VDD Supply Voltage	4.5~30	V
T_{OPT}	Operating Temperature	-40 to+85	°C

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Recommended Operating Range indicates conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Range. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{MAX} - T_A) / \theta_{JA}$ or the number given in Absolute Maximum Ratings, whichever is lower.

Note 3: Human body model, 100pF discharged through a 1.5kΩ resistor.

ELECTRICAL CHARACTERISTICS(Note 4,5)

The following specifications apply for $V_{IN}=12V$, $T_A=25^{\circ}C$, unless specified otherwise.

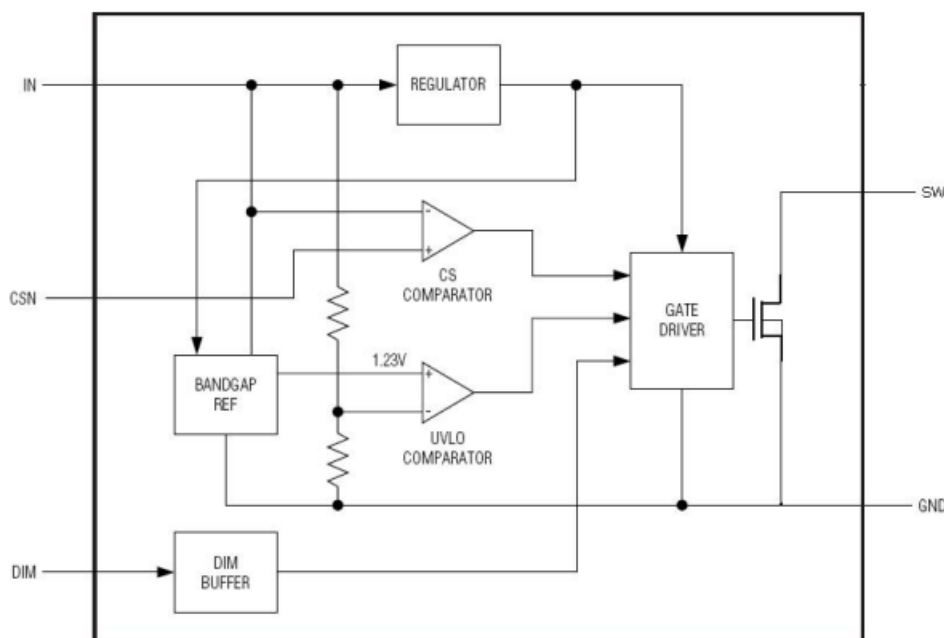
SYMBOL	ITEMS	CONDITIONS		Min.	Typ.	Max.	UNIT
V _{IN}	Input Voltage			4.5		30	V
V _{UVLO}	Under voltage lock out	V _{IN} falling			4	4.3	V
V _{UVLO,HYS}	UVLO hysteresis	V _{IN} rising			300		mV
F _{sw}	Max.Switching Frequency					1	MHz
Current Sense							
V _{CSN}	Mean current sense threshold voltage	V _{IN} -V _{CSN}	A type	95	98	101	mV
			B type	99	102	105	mV
V _{CSN_hys}	Sense threshold hysteresis				±15		%
I _{CSN}	CSN Pin Input Current	V _{IN} -V _{CSN} =50mV			8		µA
Operating Current							
I _{OFF}	Quiescent supply current with output off	V _{DIM} <0.3V			90		µA
DIM Input							
V _{DIM}	Internal supply voltage	DIM floating			4		V
V _{DIM_H}	DIM input voltage High			2.5			V
V _{DIM_L}	DIMinput voltage Low					0.3	V
V _{DIM_DC}	DC brightness control			0.5		2.5	V
f _{DIM}	Max.DIM Frequency	f _{osc} =500kHz				50	kHz
D _{pwm_LF}	Duty cycle range oflow frequency dimming	f _{DIM} =100Hz		0.02%		]	
	Brightness control range				5000:1		

ELECTRICAL CHARACTERISTICS (Continued)(Note 4,5)

SYMBOL	ITEMS	CONDITIONS	Min.	Typ.	Max.	UNIT
DIM Input						
D_{PWM_HF}	Duty cycle range of high frequency dimming	$f_{DIM}=20KHz$	4%		1	
	Brightness control range			25:1		
R_{DIM}	DIM pullup resistorto Internal supply voltage			1000		K Ω
I_{DIML}	DIM input leakage low	$V_{DIM}=0$		10		μA
Output Switch						
R_{SW}	SW On Resistance	$V_{IN}=12V$		0.4		Ω
		$V_{IN}=24V$		0.4		
I_{SWmean}	Continuous SW Current				1.2	A
I_{LEAK}	SW Leakage Current			0.5	5	μA
Thermal Shutdown						
T_{sp}	Thermal Shutdown Threshold			160		$^{\circ}C$
T_{sp-hys}	Thermal Shutdown hysteresis			20		$^{\circ}C$

Note 4: Typical parameters are measured at 25 $^{\circ}C$ and represent the parametric norm.

Note 5: Datasheet min/max specification limits are guaranteed by design,test,or statistical analysis.

SIMPLIFIED BLOCK DIAGRAM


OPERATION DESCRIPTION

The device, in conjunction with the coil (L1) and current sense resistor (RS), forms a self-oscillating continuous-mode buck converter.

When input voltage VIN is first applied, the initial current in L1 and RS is zero and there is no output from the current sense circuit. Under this condition, the output of CS comparator is high. This turns on an internal switch and switches the SW pin low, causing current to flow from VIN to ground, via RS, L1 and the LED(s). The current rises at a rate determined by VIN and L1 to produce a voltage ramp (VCSN) across RS. When (VIN - VCSN) > 115mV, the output of CS comparator switches low and the switch turns off. The current flowing on the RS decreases at another rate. When (VIN - VCSN) < 85mV, the switch turns on again and the mean current on the LED is determined by

$$\left(\frac{85 + 115}{2} \text{ mV} \right) / R_s = I_{\text{LED}} / R_s$$

The high-side current-sensing scheme and on-board current-setting circuitry minimize the number of external components while delivering LED current with ±5% accuracy, using a 1% sense resistor.

The 4115 allow dimming with a PWM signal at the DIM input. A logic level below 0.3V at DIM forces 4115 to turn off the LED and the logic level at DIM must be at least 2.5V to turn on the full LED current. The frequency of PWM dimming ranges from 100Hz to more than 20 kHz.

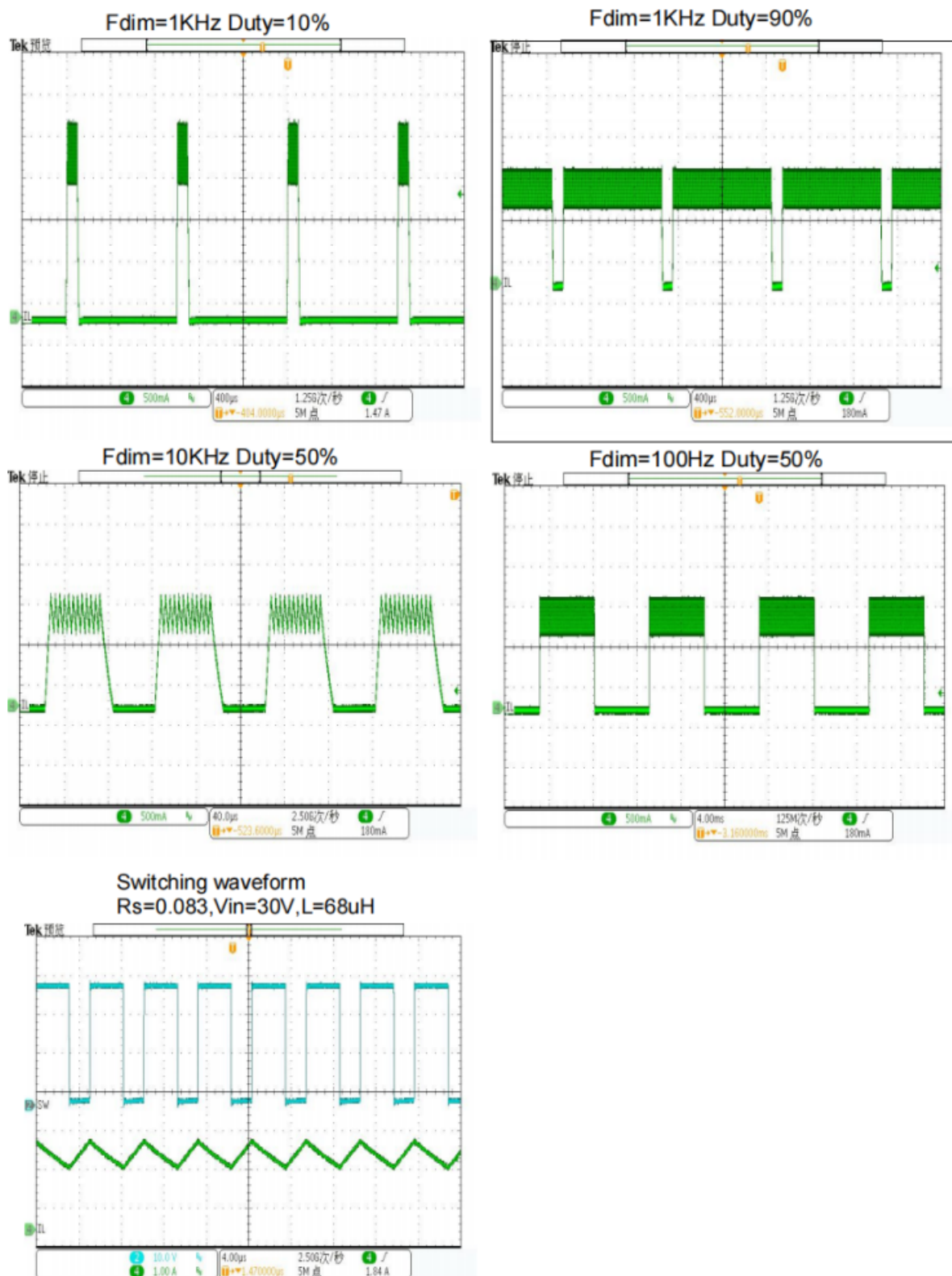
The DIM pin can be driven by an external DC voltage (VDIM) to adjust the output current to a value below the nominal average value defined by RS. The DC voltage is valid from 0.5V to 2.5V. When the dc voltage is higher than 2.5V, the output current keeps constant. The LED current also can be adjusted by a resistor connected to the DIM pin. An internal pull-up resistor (typical 1000KΩ) is connected to a 5V internal regulator. The voltage of DIM pin is divided by the internal and external resistor.

The DIM pin is pulled up to the internal regulator (5V) by a 1000KΩ resistor. It can be floated at normal working. When a voltage applied to DIM falls below the threshold (0.3V nom.), the output switch is turned off. The internal regulator and voltage reference remain powered during shutdown to provide the reference for the shutdown circuit. Quiescent supply current during shutdown is nominally 90uA and switch leakage is below 5uA.

Additionally, to ensure the reliability, the 4115 is built with a thermal shutdown (TSD) protection and a thermal

pad. The TSD protects the IC from over temperature (160°C). Also the thermal pad enhances power dissipation. As a result, the 4115 can handle a large amount of current safely.

TYPICAL PERFORMANCE CHARACTERISTICS



APPLICATION NOTES

Setting nominal average output current with external resistor RS

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor (RS)

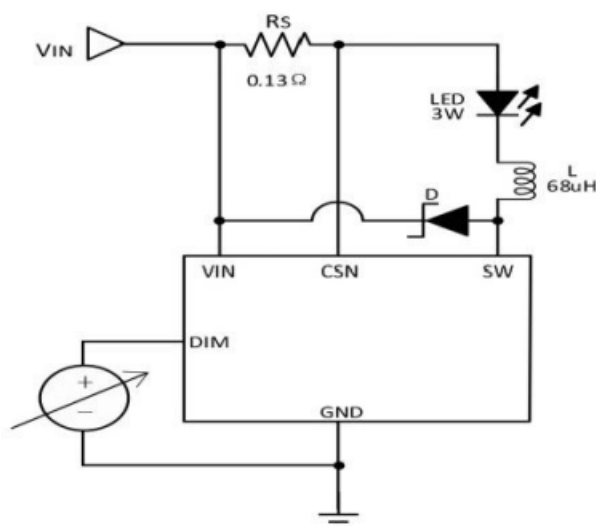
connected between VIN and CSN and is given by:

$$I_{OUT} = 0.1 / R_s (R_s \geq 0.082 \Omega)$$

This equation is valid when DIM pin is float or applied with a voltage higher than 2.5V (must be less than 5V). Actually, RS sets the maximum average current which can be adjusted to a less one by dimming.

Output current adjustment by external DC control voltage

The DIM pin can be driven by an external dc voltage (VDIM), as shown, to adjust the output current to a value below the nominal average value defined by RS.



The average output current is given by: $I_{OUT} = \frac{0.1 \times V_{DIM}}{2.5 \times R_s} (0.5V \leq V_{DIM} \leq 2.5V)$

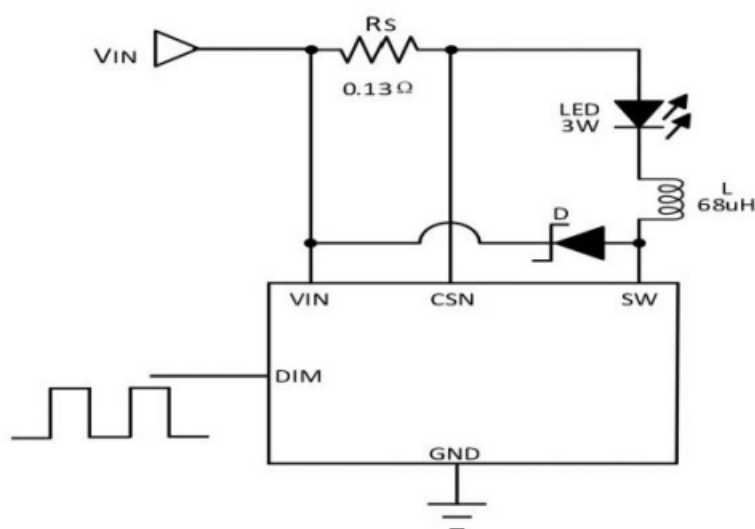
Note that 100% brightness setting corresponds to: $(2.5V \leq V_{DIM} \leq 5V)$

Output current adjustment by PWM control

A Pulse Width Modulated (PWM) signal with duty cycle PWM can be applied to the DIM pin, as shown below, to adjust the output current to a value below the nominal average value set by resistor RS:

$$I_{OUT} = \frac{0.1 \times D}{R_s} (0 \leq D \leq 100\%, 2.5V < V_{pulse} < 5V)$$

$$I_{OUT} = \frac{V_{pulse} \times 0.1 \times D}{2.5 \times R_s} (0 \leq D \leq 100\%, 0.5V < V_{pulse} < 2.5V)$$



PWM dimming provides reduced brightness by modulating the LED's forward current between 0% and 100%. The LED brightness is controlled by adjusting the relative ratios of the on time to the off time. A 25% brightness level is achieved by turning the LED on at full current for 25% of one cycle. To ensure this switching process between on and off state is invisible by human eyes, the switching frequency must be greater than 100 Hz. Above 100 Hz, the human eyes average the on and off times, seeing only an effective brightness that is proportional to the LED's on-time duty cycle. The advantage of PWM dimming is that the forward current is always constant, therefore the LED color does not vary with brightness as it does with analog dimming. Pulsing the current provides precise brightness control while preserving the color purity. The dimming frequency of 4115 can be as high as 20kHz.

Shutdown mode

Taking the DIM pin to a voltage below 0.3V will turn off the output and the supply current will fall to a low standby level of 90μA nominal.

Soft-start

An external capacitor from the DIM pin to ground will provide additional soft-start delay, by increasing the time taken for the voltage on this pin to rise to the turn-on threshold and by slowing down the rate of rise of the control voltage at the input of the comparator. Adding capacitance increases this delay by approximately 0.8ms/nF.

Inherent open-circuit LED protection

If the connection to the LED(s) is open-circuited, the coil is isolated from the SW pin of the chip, so the device and LED will not be damaged.

Capacitor selection

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply. A minimum value of 4.7μF is

acceptable if the DC input source is close to the device, but higher values will improve performance at lower input voltages, especially when the source impedance is high. For the rectified AC input, the capacitor should be higher than 100uF and the tantalum capacitor is recommended. The input capacitor should be placed as close as possible to the IC. For maximum stability over temperature and voltage, capacitors with X7R, X5R, or better dielectric are recommended. Capacitors with Y5V dielectric are not suitable for decoupling in this application and should NOT be used. A suitable Murata capacitor would be GRM42-2X7R475K-50. The following web sites are useful when finding alternatives:

Inductor selection

Recommended inductor values for the 4115 are in the range 27uH to 100uH. Higher values of inductance are recommended at lower output current in order to minimize errors due to switching delays, which result in increased ripple and lower efficiency. Higher values of inductance also result in a smaller change in output current over the supply voltage range. (See graphs). The inductor should be mounted as close to the device as possible with low resistance connections to the SW and VIN pins.

The chosen coil should have a saturation current higher than the peak output current and a continuous current rating above the required mean output current.

Following table gives the guideline on inductor selection:

Load current	Inductor	Saturation current
$I_{out} > 1A$	27-47uH	1.3-1.5 times of load current
$0.8A < I_{out} \leq 1A$	33-82uH	
$0.4A < I_{out} \leq 0.8A$	47-100uH	
$I_{out} \leq 0.4A$	68-220uH	

Suitable coils for use with the 4115 are listed in the table below:

Part No.	L (uH)	DCR (2)	IsAT(A)	Manufacturer
MSS1038-333	27	0.089	2.48	CoilCraft
MSS1038-333	33	0.093	2.3	
MSS1038-473	47	0.128	2	
MSS1038-683	68	0.213	1.6	
MSS1038-104	100	0.304	1.3	

The inductor value should be chosen to maintain operating duty cycle and switch 'on'/'off' times within the specified limits over the supply voltage and load current range. The following equations can be used as a guide.

SW Switch 'On' time

$$T_{ON} = \frac{L \times \Delta I}{V_{IN} - V_{LED} - I_{avg} \times (R_S + R_L + R_{sw})}$$

SW Switch 'Off' time

$$T_{OFF} = \frac{L \times \Delta I}{V_{LED} + V_D + I_{avg} \times (R_s + r_L)}$$

Where:

L is the coil inductance(H)

R_L is the coil resistance(Ω)

R_s is the current sense resistance(Ω)

I_{avg} is the required LED current(A)

ΔI is the coil peak-peak ripple current(A){Internally set to 0.3x I_{avg}} VIN is the supply voltage(V)

V_{LED} is the total LED forward voltage(V)

R_{sw} is the switch resistance(Ω){=0.6Ω nominal}

V_D is the diode forward voltage at the required load current(V)

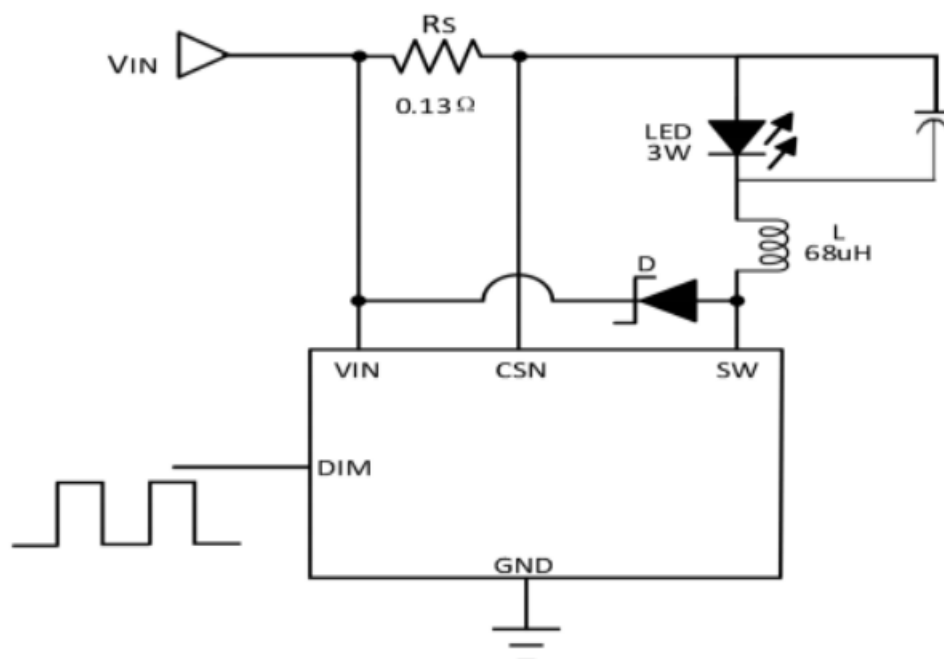
Diode selection

For maximum efficiency and performance, the rectifier(D1) should be a fast low capacitance Schottky diode with low reverse leakage at the maximum operating voltage and temperature. They also provide better efficiency than silicon diodes, due to a combination of lower forward voltage and reduced recovery time. It is important to select parts with a peak current rating above the peak coil current and a continuous current rating higher than the maximum output load current. It is very important to consider the reverse leakage of the diode when operating above 85°C. Excess leakage will increase the power dissipation in the device and if close to the load may create a thermal runaway condition.

The higher forward voltage and overshoot due to reverse recovery time in silicon diodes will increase the peak voltage on the SW output. If a silicon diode is used, care should be taken to ensure that the total voltage appearing on the SW pin including supply ripple, does not exceed the specified maximum value. The following web sites are useful when finding alternatives:

Reducing output ripple

Peak to peak ripple current in the LED(s) can be reduced, if required, by shunting a capacitor C_{LED} across the LED(s) as shown below:



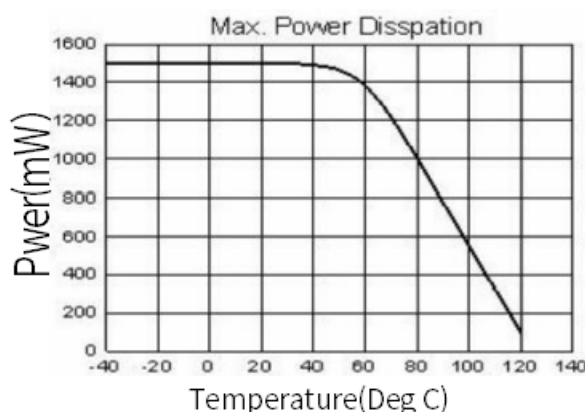
A value of 1μF will reduce the supply ripple current by a factor three (approx.).Proportionally lower ripple can be achieved with higher capacitor values.Note that the capacitor will not affect operating frequency or efficiency, but it will increase start-up delay and reduce the frequency of dimming,by reducing the rate of rise of LED voltage.By adding this capacitor the current waveform through the LED(s)changes from a triangular ramp to a more sinusoidal version without altering the mean current value.

Operation at low supply voltage

The internal regulator disables the drive to the switch until the supply has risen above the startup threshold (VUVLO).Above this threshold,the device will start to operate.However,with the supply voltage below the specified minimum value,the switch duty cycle will be high and the device power dissipation will be at a maximum.Care should be taken to avoid operating the device under such conditions in the application,in order to minimize the risk of exceeding the maximum allowed die temperature.(See next section on thermal considerations).The drive to the switch is turned off when the supply voltage falls below the under-voltage threshold(VUVLO-0.5V).This prevents the switch working with excessive'on'resistance under conditions where the duty cycle is high.

Thermal considerations

When operating the device at high ambient temperatures,or when driving maximum load current,care must be taken to avoid exceeding the package power dissipation limits.The graph below gives details for power derating. This assumes the device to be mounted on a 25mm² PCB with 1oz copper standing in still air.



Note that the device power dissipation will most often be a maximum at minimum supply voltage. It will also increase if the efficiency of the circuit is low. This may result from the use of unsuitable coils, or excessive parasitic output capacitance on the switch output. When the application is limited by the internal power dissipation of the device, the ESOP8 package is recommended because of its enhanced power dissipation ability.

Thermal compensation of output current

High luminance LEDs often need to be supplied with a temperature compensated current in order to maintain stable and reliable operation at all drive levels. The LEDs are usually mounted remotely from the device so, for this reason, the temperature coefficients of the internal circuits for the 4115 have been optimized to minimize

the change in output current when no compensation is employed. If output current compensation is required, it is possible to use an external temperature sensing network—normally using Negative Temperature Coefficient (NTC) thermistors and/or diodes, mounted very close to the LED(s). The output of the sensing network can be used to drive the DIM pin in order to reduce output current with increasing temperature.

Thermal shutdown protection

To ensure the reliability, the 4115 is built with a thermal shutdown (TSD) protection function. The TSD protects the IC from over temperature (160°C). When the chip temperature decreases (140°C), the IC recovers again.

Layout considerations

Careful PCB layout is critical to achieve low switching losses and stable operation. Use a multilayer board whenever possible for better noise immunity. Minimize ground noise by connecting high-current ground returns, the input bypass-capacitor ground lead, and the output-filter ground lead to a single point (star ground configuration).

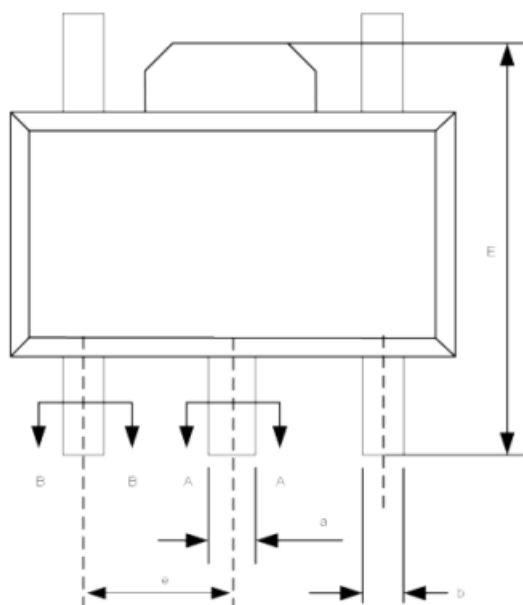
SW pin

The SW pin of the device is a fast switching node, so PCB tracks should be kept as short as possible. To minimize ground 'bounce', the ground pin of the device should be soldered directly to the ground plane. Coil and decoupling capacitors and current sense resistor It is particularly important to mount the coil and the input decoupling capacitor as close to the device pins as possible to minimize parasitic resistance and

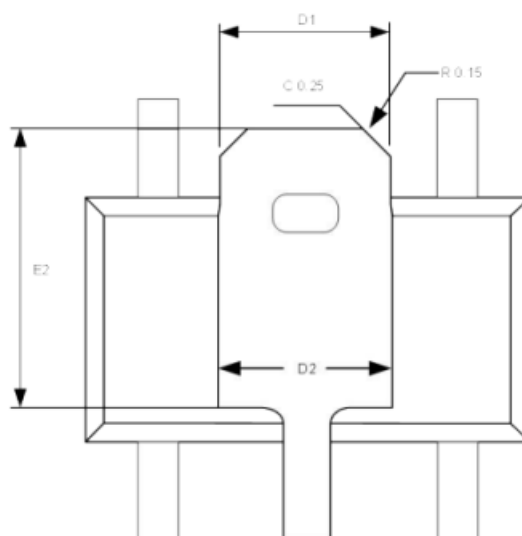
inductance, which will degrade efficiency. It is also important to minimize any track resistance in series with current sense resistor R_S . It's best to connect VIN directly to one end of R_S and CSN directly to the opposite end of R_S with no other currents flowing in these tracks. It is important that the cathode current of the Schottky diode does not flow in a track between R_S and VIN as this may give an apparent higher measure of current than is actual because of track resistance.

PACKAGE DESCRIPTION

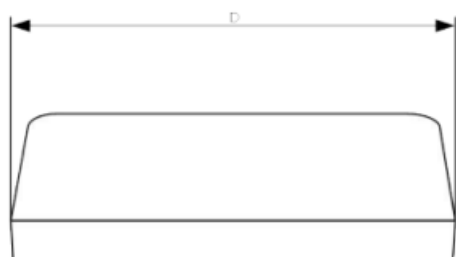
SOT89-5



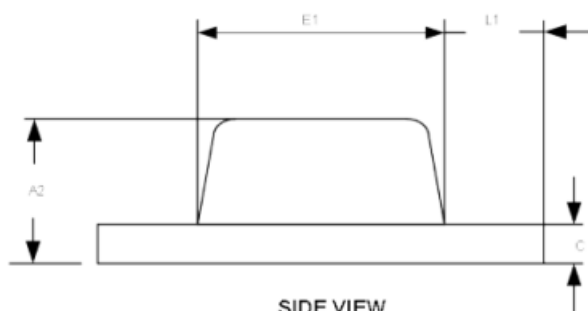
TOP VIEW



BOTTOM VIEW



FRONT VIEW



SIDE VIEW

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A2	1.40	1.50	1.60
b	0.38	-	0.46
a	0.46	-	0.56
D	4.40	4.50	4.60
E	4.00	4.20	4.40
E1	2.40	2.50	2.60
e	1.50BSC		
L1	0.80	1.00	1.20

Size(mm)	D1	D2	E2
L/F Size(mil)			
85×70	1.70REF	1.75REF	2.84REF

- NOTE:
1. CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
 2. PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 3. PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
 4. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
 5. DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA.
 6. DRAWING IS NOT TO SCALE.

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